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Kind regards,

Team Nexperia

# PEMB18; PUMB18

PNP/PNP resistor-equipped transistors;  
R1 = 4.7 k $\Omega$ , R2 = 10 k $\Omega$

Rev. 5 — 21 December 2011

Product data sheet

## 1. Product profile

### 1.1 General description

PNP/PNP double Resistor-Equipped Transistors (RET) in Surface-Mounted Device (SMD) plastic packages.

Table 1. Product overview

| Type number | Package |       | NPN/PNP complement | NPN/NPN complement | Package configuration     |
|-------------|---------|-------|--------------------|--------------------|---------------------------|
|             | NXP     | JEITA |                    |                    |                           |
| PEMB18      | SOT666  | -     | PEMD18             | PEMH18             | ultra small and flat lead |
| PUMB18      | SOT363  | SC-88 | PUMD18             | PUMH18             | very small                |

### 1.2 Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified

### 1.3 Applications

- Low current peripheral driver
- Control of IC inputs
- Replaces general-purpose transistors in digital applications

### 1.4 Quick reference data

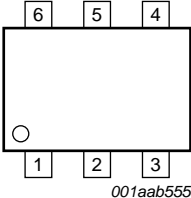
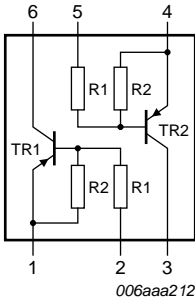
Table 2. Quick reference data

| Symbol                | Parameter                 | Conditions | Min | Typ | Max  | Unit       |
|-----------------------|---------------------------|------------|-----|-----|------|------------|
| <b>Per transistor</b> |                           |            |     |     |      |            |
| V <sub>CEO</sub>      | collector-emitter voltage | open base  | -   | -   | -50  | V          |
| I <sub>O</sub>        | output current            |            | -   | -   | -100 | mA         |
| R1                    | bias resistor 1 (input)   |            | 3.3 | 4.7 | 6.1  | k $\Omega$ |
| R2/R1                 | bias resistor ratio       |            | 1.7 | 2.1 | 2.6  |            |



## 2. Pinning information

Table 3. Pinning

| Pin | Description            | Simplified outline                                                                  | Graphic symbol                                                                      |
|-----|------------------------|-------------------------------------------------------------------------------------|-------------------------------------------------------------------------------------|
| 1   | GND (emitter) TR1      |  |  |
| 2   | input (base) TR1       |                                                                                     |                                                                                     |
| 3   | output (collector) TR2 |                                                                                     |                                                                                     |
| 4   | GND (emitter) TR2      |                                                                                     |                                                                                     |
| 5   | input (base) TR2       |                                                                                     |                                                                                     |
| 6   | output (collector) TR1 |                                                                                     |                                                                                     |

## 3. Ordering information

Table 4. Ordering information

| Type number | Package |                                          | Version |
|-------------|---------|------------------------------------------|---------|
|             | Name    | Description                              |         |
| PEMB18      | -       | plastic surface-mounted package; 6 leads | SOT666  |
| PUMB18      | SC-88   | plastic surface-mounted package; 6 leads | SOT363  |

## 4. Marking

Table 5. Marking codes

| Type number | Marking code <sup>[1]</sup> |
|-------------|-----------------------------|
| PEMB18      | 6A                          |
| PUMB18      | B8*                         |

[1] \* = placeholder for manufacturing site code

## 5. Limiting values

**Table 6. Limiting values**

*In accordance with the Absolute Maximum Rating System (IEC 60134).*

| Symbol                | Parameter                 | Conditions                             | Min    | Max  | Unit |    |
|-----------------------|---------------------------|----------------------------------------|--------|------|------|----|
| <b>Per transistor</b> |                           |                                        |        |      |      |    |
| V <sub>CBO</sub>      | collector-base voltage    | open emitter                           | -      | -50  | V    |    |
| V <sub>CEO</sub>      | collector-emitter voltage | open base                              | -      | -50  | V    |    |
| V <sub>EBO</sub>      | emitter-base voltage      | open collector                         | -      | -7   | V    |    |
| V <sub>I</sub>        | input voltage             |                                        |        |      |      |    |
|                       | positive                  |                                        | -      | +7   | V    |    |
|                       | negative                  |                                        | -      | -20  | V    |    |
| I <sub>O</sub>        | output current            |                                        | -      | -100 | mA   |    |
| I <sub>CM</sub>       | peak collector current    | single pulse;<br>t <sub>p</sub> ≤ 1 ms | -      | -100 | mA   |    |
| P <sub>tot</sub>      | total power dissipation   | T <sub>amb</sub> ≤ 25 °C               |        |      |      |    |
|                       | PEMB18 (SOT666)           |                                        | [1][2] | -    | 200  | mW |
|                       | PUMB18 (SOT363)           |                                        | [1]    | -    | 200  | mW |
| <b>Per device</b>     |                           |                                        |        |      |      |    |
| P <sub>tot</sub>      | total power dissipation   | T <sub>amb</sub> ≤ 25 °C               |        |      |      |    |
|                       | PEMB18 (SOT666)           |                                        | [1][2] | -    | 300  | mW |
|                       | PUMB18 (SOT363)           |                                        | [1]    | -    | 300  | mW |
| T <sub>j</sub>        | junction temperature      |                                        | -      | 150  | °C   |    |
| T <sub>amb</sub>      | ambient temperature       |                                        | -65    | +150 | °C   |    |
| T <sub>stg</sub>      | storage temperature       |                                        | -65    | +150 | °C   |    |

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.



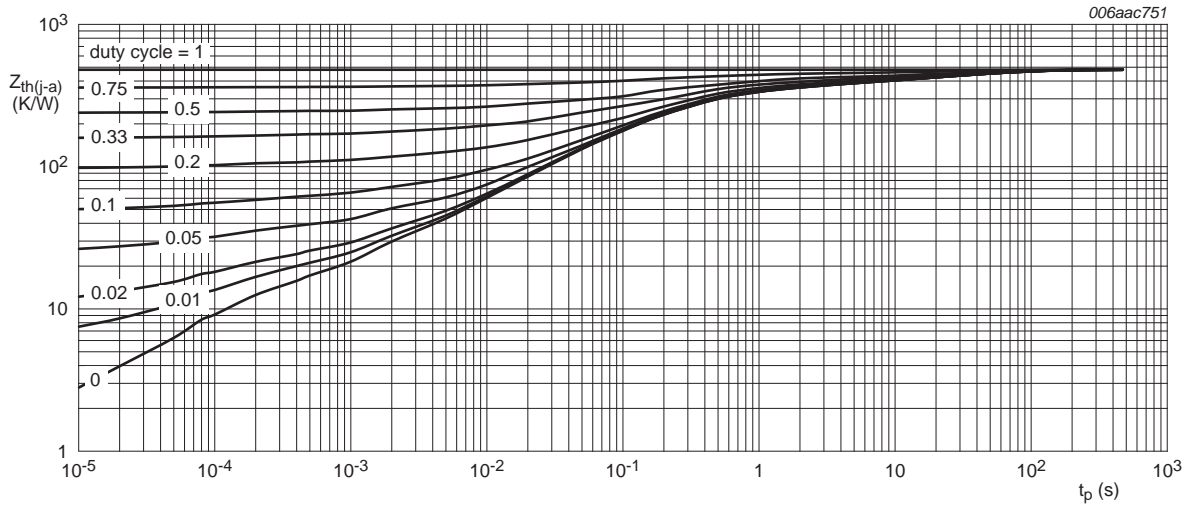
## 6. Thermal characteristics

**Table 7. Thermal characteristics**

| Symbol                | Parameter                                   | Conditions  | Min    | Typ | Max | Unit |
|-----------------------|---------------------------------------------|-------------|--------|-----|-----|------|
| <b>Per transistor</b> |                                             |             |        |     |     |      |
| $R_{th(j-a)}$         | thermal resistance from junction to ambient | in free air |        |     |     |      |
|                       | PEMB18 (SOT666)                             |             | [1][2] | -   | 625 | K/W  |
|                       | PUMB18 (SOT363)                             |             | [1]    | -   | 625 | K/W  |
| <b>Per device</b>     |                                             |             |        |     |     |      |
| $R_{th(j-a)}$         | thermal resistance from junction to ambient | in free air |        |     |     |      |
|                       | PEMB18 (SOT666)                             |             | [1][2] | -   | 417 | K/W  |
|                       | PUMB18 (SOT363)                             |             | [1]    | -   | 417 | K/W  |

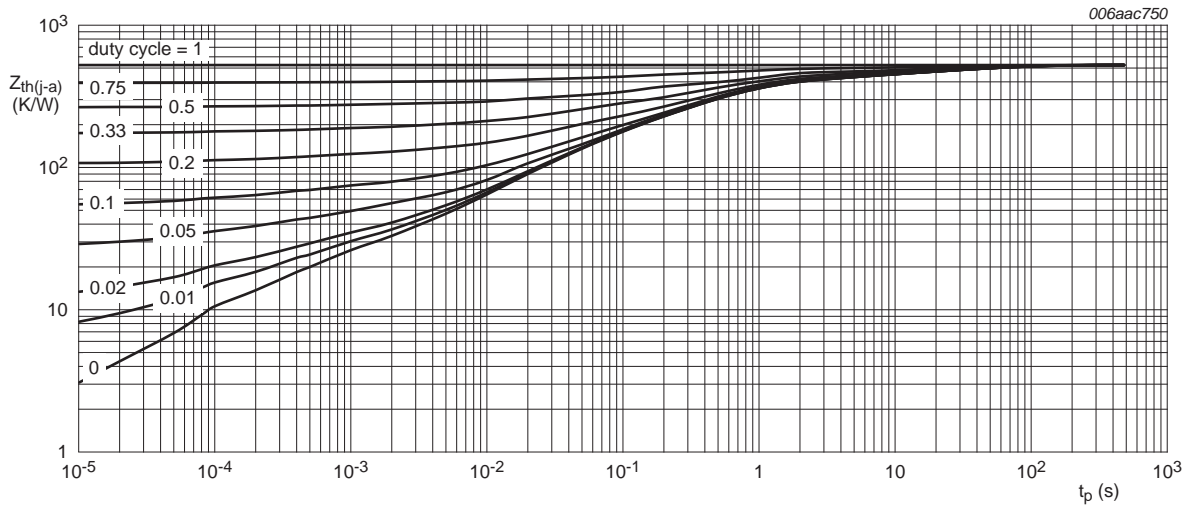
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.



FR4 PCB, standard footprint

**Fig 2. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration for PEMB18 (SOT666); typical values**



FR4 PCB, standard footprint

**Fig 3. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration for PUMB18 (SOT363); typical values**

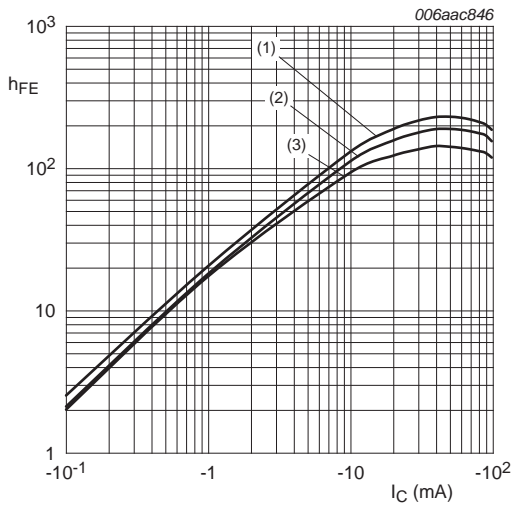
## 7. Characteristics

**Table 8. Characteristics**

$T_{amb} = 25\text{ °C}$  unless otherwise specified.

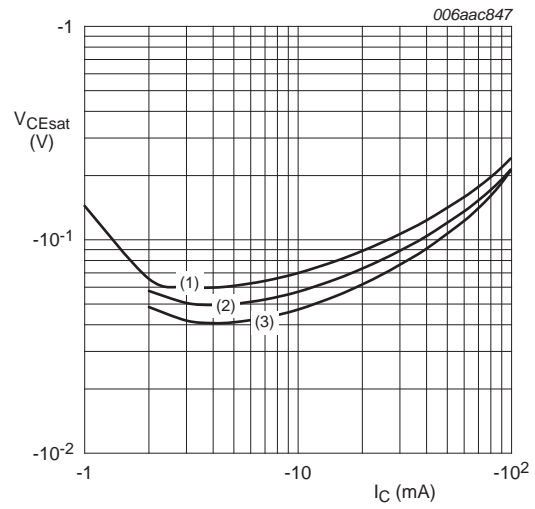
| Symbol                | Parameter                            | Conditions                                                                               | Min  | Typ  | Max  | Unit |
|-----------------------|--------------------------------------|------------------------------------------------------------------------------------------|------|------|------|------|
| <b>Per transistor</b> |                                      |                                                                                          |      |      |      |      |
| $I_{CBO}$             | collector-base cut-off current       | $V_{CB} = -50\text{ V}; I_E = 0\text{ A}$                                                | -    | -    | -100 | nA   |
| $I_{CEO}$             | collector-emitter cut-off current    | $V_{CE} = -30\text{ V}; I_B = 0\text{ A}$                                                | -    | -    | -1   | μA   |
|                       |                                      | $V_{CE} = -30\text{ V}; I_B = 0\text{ A}; T_j = 150\text{ °C}$                           | -    | -    | -5   | μA   |
| $I_{EBO}$             | emitter-base cut-off current         | $V_{EB} = -5\text{ V}; I_C = 0\text{ A}$                                                 | -    | -    | -600 | μA   |
| $h_{FE}$              | DC current gain                      | $V_{CE} = -5\text{ V}; I_C = -10\text{ mA}$                                              | 50   | -    | -    |      |
| $V_{CEsat}$           | collector-emitter saturation voltage | $I_C = -10\text{ mA}; I_B = -0.5\text{ mA}$                                              | -    | -    | -100 | mV   |
| $V_{I(off)}$          | off-state input voltage              | $V_{CE} = -5\text{ V}; I_C = -100\text{ μA}$                                             | -    | -0.9 | -0.3 | V    |
| $V_{I(on)}$           | on-state input voltage               | $V_{CE} = -0.3\text{ V}; I_C = -20\text{ mA}$                                            | -2.5 | -1.5 | -    | V    |
| R1                    | bias resistor 1 (input)              |                                                                                          | 3.3  | 4.7  | 6.1  | kΩ   |
| R2/R1                 | bias resistor ratio                  |                                                                                          | 1.7  | 2.1  | 2.6  |      |
| $C_c$                 | collector capacitance                | $V_{CB} = -10\text{ V}; I_E = i_e = 0\text{ A}; f = 1\text{ MHz}$                        | -    | -    | 3    | pF   |
| $f_T$                 | transition frequency                 | $V_{CE} = -5\text{ V}; I_C = -10\text{ mA};$ <a href="#">[1]</a><br>$f = 100\text{ MHz}$ | -    | 180  | -    | MHz  |

[1] Characteristics of built-in transistor



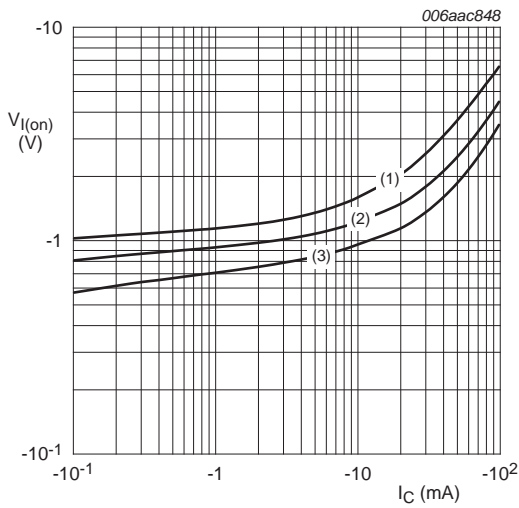
$V_{CE} = -5\text{ V}$   
 (1)  $T_{amb} = 100\text{ }^{\circ}\text{C}$   
 (2)  $T_{amb} = 25\text{ }^{\circ}\text{C}$   
 (3)  $T_{amb} = -40\text{ }^{\circ}\text{C}$

**Fig 4. DC current gain as a function of collector current; typical values**



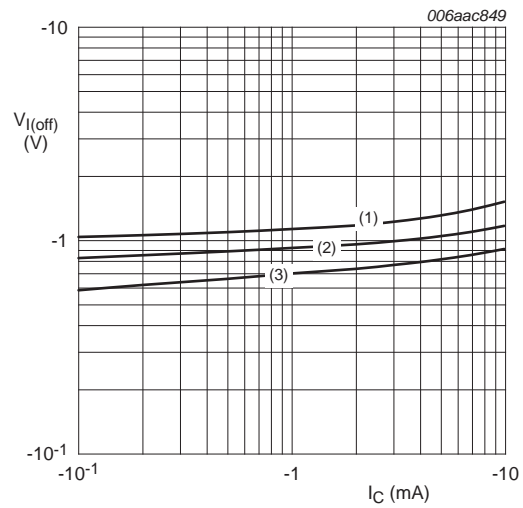
$I_C/I_B = 20$   
 (1)  $T_{amb} = 100\text{ }^{\circ}\text{C}$   
 (2)  $T_{amb} = 25\text{ }^{\circ}\text{C}$   
 (3)  $T_{amb} = -40\text{ }^{\circ}\text{C}$

**Fig 5. Collector-emitter saturation voltage as a function of collector current; typical values**



$V_{CE} = -0.3\text{ V}$   
 (1)  $T_{amb} = -40\text{ }^{\circ}\text{C}$   
 (2)  $T_{amb} = 25\text{ }^{\circ}\text{C}$   
 (3)  $T_{amb} = 100\text{ }^{\circ}\text{C}$

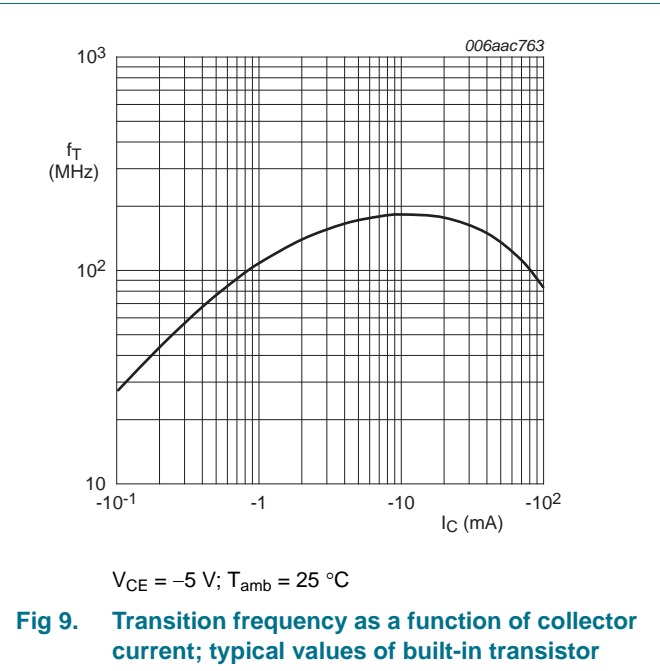
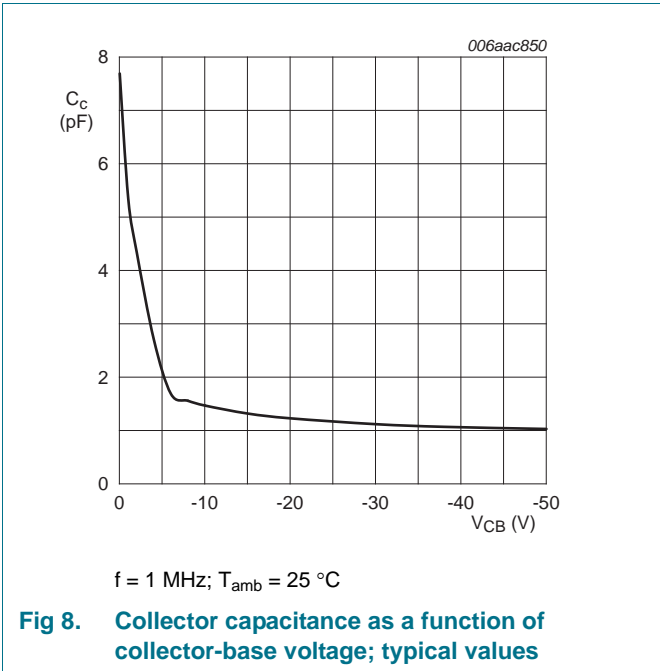
**Fig 6. On-state input voltage as a function of collector current; typical values**



$V_{CE} = -5\text{ V}$   
 (1)  $T_{amb} = -40\text{ }^{\circ}\text{C}$   
 (2)  $T_{amb} = 25\text{ }^{\circ}\text{C}$   
 (3)  $T_{amb} = 100\text{ }^{\circ}\text{C}$

**Fig 7. Off-state input voltage as a function of collector current; typical values**



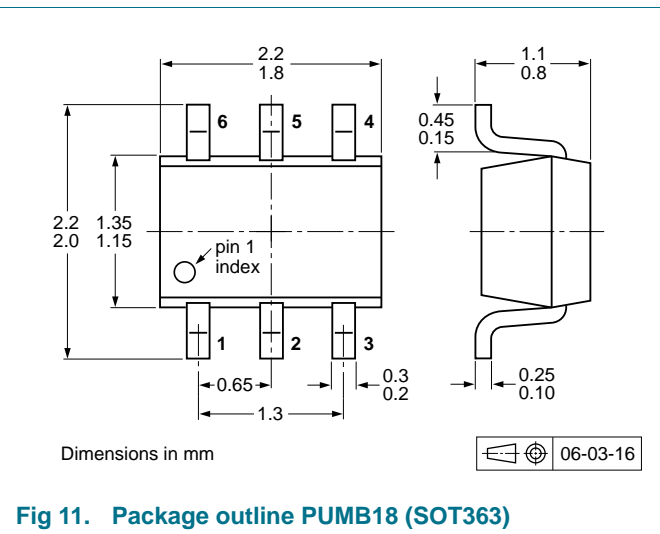
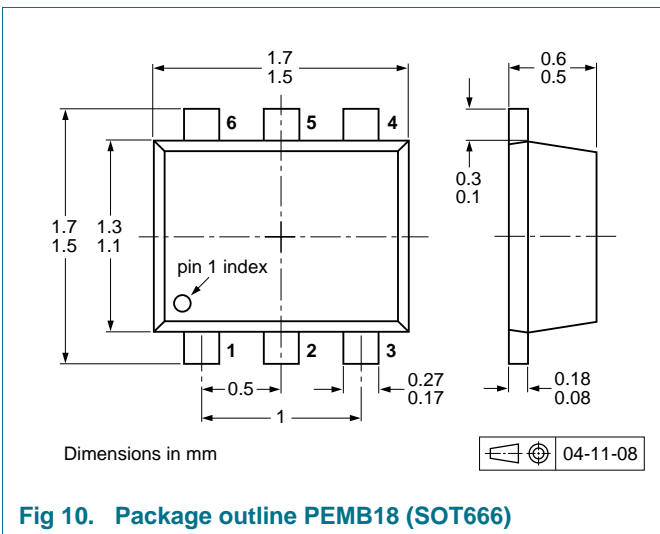


**8. Test information**

**8.1 Quality information**

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

**9. Package outline**



10. Packing information

Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.<sup>[1]</sup>

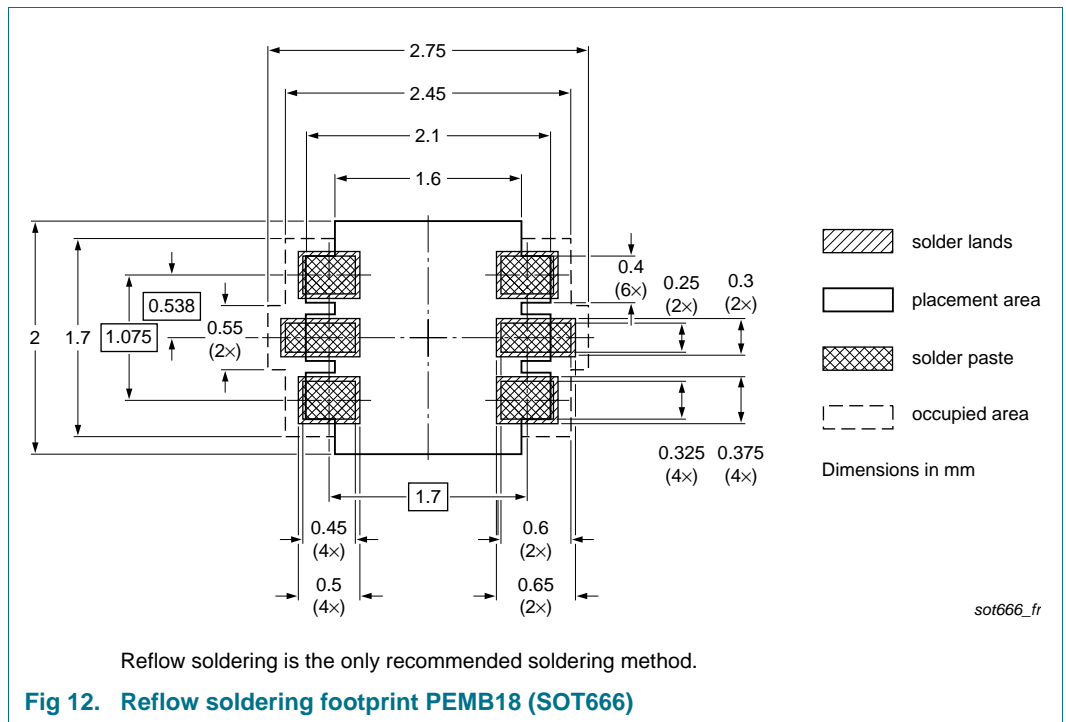
| Type number | Package | Description                                       | Packing quantity |      |      |       |
|-------------|---------|---------------------------------------------------|------------------|------|------|-------|
|             |         |                                                   | 3000             | 4000 | 8000 | 10000 |
| PEMB18      | SOT666  | 2 mm pitch, 8 mm tape and reel                    | -                | -    | -315 | -     |
|             |         | 4 mm pitch, 8 mm tape and reel                    | -                | -115 | -    | -     |
| PUMB18      | SOT363  | 4 mm pitch, 8 mm tape and reel; T1 <sup>[2]</sup> | -115             | -    | -    | -135  |
|             |         | 4 mm pitch, 8 mm tape and reel; T2 <sup>[3]</sup> | -125             | -    | -    | -165  |

[1] For further information and the availability of packing methods, see [Section 14](#).

[2] T1: normal taping

[3] T2: reverse taping

11. Soldering



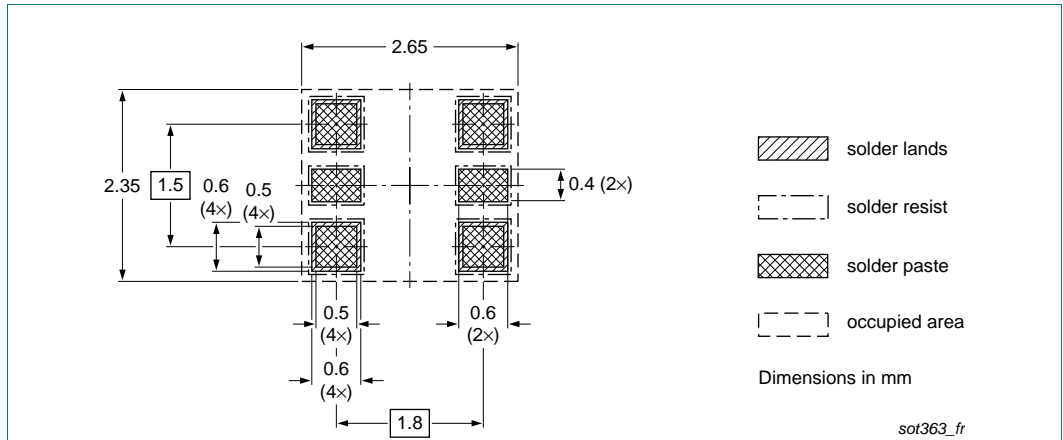


Fig 13. Reflow soldering footprint PUMB18 (SOT363)

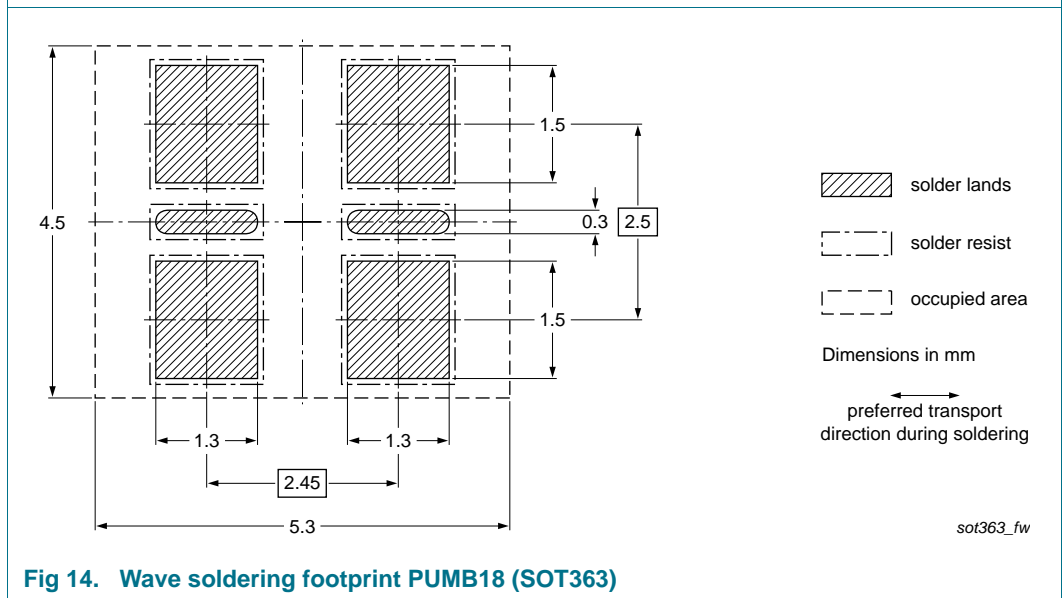


Fig 14. Wave soldering footprint PUMB18 (SOT363)

## 12. Revision history

**Table 10. Revision history**

| Document ID       | Release date                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                            | Data sheet status     | Change notice | Supersedes        |
|-------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----------------------|---------------|-------------------|
| PEMB18_PUMB18 v.5 | 20111221                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                | Product data sheet    | -             | PEMB18_PUMB18 v.4 |
| Modifications:    | <ul style="list-style-type: none"> <li>• <a href="#">Section 1 “Product profile”</a>: updated</li> <li>• <a href="#">Section 4 “Marking”</a>: updated</li> <li>• <a href="#">Figure 1 to 3, 8 and 9</a>: added</li> <li>• <a href="#">Section 6 “Thermal characteristics”</a>: updated</li> <li>• <a href="#">Figure 4 to 7</a>: updated</li> <li>• <a href="#">Table 8 “Characteristics”</a>: I<sub>CEO</sub> and V<sub>CEsat</sub> updated, f<sub>T</sub> added</li> <li>• <a href="#">Section 8 “Test information”</a>: added</li> <li>• <a href="#">Section 11 “Soldering”</a>: added</li> <li>• <a href="#">Section 13 “Legal information”</a>: updated</li> </ul> |                       |               |                   |
| PEMB18_PUMB18 v.4 | 20090901                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                | Product data sheet    | -             | PEMB18_PUMB18 v.3 |
| PEMB18_PUMB18 v.3 | 20050708                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                | Product data sheet    | -             | PEMB18_PUMB18 v.2 |
| PEMB18_PUMB18 v.2 | 20050202                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                | Product data sheet    | -             | PUMB18 v.1        |
| PUMB18 v.1        | 20031003                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                | Product specification | -             | -                 |

## 13. Legal information

### 13.1 Data sheet status

| Document status <sup>[1][2]</sup> | Product status <sup>[3]</sup> | Definition                                                                            |
|-----------------------------------|-------------------------------|---------------------------------------------------------------------------------------|
| Objective [short] data sheet      | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet    | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet        | Production                    | This document contains the product specification.                                     |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



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